Study of deoxidization process of Csl melt by the action of "Zr-Pt" galvanic couple

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The course of removal of oxide ion admixtures (deoxidization) from molten cesium iodide using galvanic couple "zirconium-platinum" at 973 K was studied by a potentiometric method using a membrane oxygen electrode $Pt(O_2)|YSZ$ (YSZ — yttria stabilized zirconia) as an indicator one for the detection of current and equilibrium concentrations of O^{2-} . The running of the deoxidization in both cases is subjected to kinetics of 2^{nd} order process with respect to O^{2-} and the rate constant is as $(3.07\pm0.31)\cdot10^6$ kg·mol⁻¹·min⁻¹·cm⁻² for the galvanic couple. Surface capacity of the galvanic couple with respect to oxide ions was estimated as $7.6\cdot10^{-4}$ mol·cm⁻². The destruction and fixation of oxygen-containing admixtures in the case of the galvanic couple occur more intensively that in the case of pure zirconium and "Zr-Pt" combination is more promising agent for deep purification of growth halide melts.

Keywords: melt processing, cesium iodide, deoxidization, zirconium, rate constant, surface capacity.

Представлены результаты исследования процесса очистки расплава йодида цезия от кислородсодержащих примесей с помощью гальванической пары "Zr-Pt" при 973 К. Для определения текущей и равновесной концентрации O²⁻ использовали потенциометрическую ячейку с мембранным кислородным электродом Pt(O₂)|YSZ(YSZ-0.9ZrO₂+0.1Y₂O₃). Процесс раскисления протекает по уравнению II порядка по отношению к O²⁻, соответствующая константа скорости равна (3.07 ± 0.31)·10⁶ кг·моль⁻¹.мин⁻¹.см⁻². Поверхностная емкость циркония по O²⁻ составляет 7.6·10⁻⁴ моль·см⁻². Процесс разрушения и связывания кислородсодержащих примесей при использовании гальванической пары протекает более интенсивно,чем при использовании чистого циркония, и она является более перспективным агентом для глубокой очистки ростовых галогенидных расплавов.

Вивчення процесу розкислення розтопу Csl дією гальванічної пари "Zr-Pt". В.Л.Чергинець, Т.П.Реброва, Ю.М.Дацько, О.Л.Ребров, П.В.Матейченко.

Наведено результати дослідження процесу очистки розтопу йодиду цезію від оксигенвмісних домішок за допомогою гальванічної пари "Zr-Pt" при 973 К. Для визначення поточної і рівноважної концентрації O²⁻ використано потенціометричну комірку з мембранним оксигеновим електродом Pt(O₂)|YSZ(YSZ-0.9ZrO₂+0.1Y₂O₃). Перебіг процесу розкислення відбувається у відповідності з рівнянням ІІ порядку відносно O²⁻, константа швидкості дорівнює $(3.07 \pm 0.31) \cdot 10^6$ кг·моль⁻¹·мин⁻¹·см⁻². Поверхнева ємність цирконію відносно O²⁻ оцінюється у 7.6·10⁻⁴ моль·см⁻². Процес руйнування і зв'язування оксигенвмісних домішок при використанні гальванічної пари протікає більш інтенсивно ніж при використанні чистого цирконію, вона є більш перспективним агентом для глибокої очистки ростових галогенідних розтопів.

1.Introduction

Single crystals of pure cesium iodide are widely used as one of the best materials for optical details transparent for IR radiation [1]. Another well-known application of undoped Cs is connected with high-energy physics: it is used as scintillator stable under action of very intensive fluxes of high-energy particles [2]. For both Csl applications oxygen-containing admixtures (mainly, hydroxide and carbonate) are very undesirable since their inclusion into the crystals leads to appearance of absorption bands in IR region. Ditto, the presence of carbonates or hydroxides makes the single crystals hygroscopic and hydrogen-containing ions formed because of crystal hydrolysis:

$$\mathrm{CO}_3^{2-} + \mathrm{H}_2\mathrm{O} \to \mathrm{HCO}_3^- + \mathrm{OH}^-$$
(1)

are very prone to radiolysis with the formation of coloring centers worsening the transparency and performance of the crystals [3]. Therefore, the problem of deep deoxidization of Csl melt is very urgent for creation of halide single crystals of excellent optical quality.

As is known, oxygen-containing admixtures enter into halide raw for crystal growth in all the stages of its preparation: synthesis of initial chemicals, heating in vacuum, melting and immediately following growth procedure. Naturally, the purification of the melt immediately before the growth process should be the most efficient. Although there are few ways of purification of Csl in molten state some of them, e.g. purification by gaseous hydrogen iodide, cannot be recommended for industrial purposes because of great corrosion activity of the halogenating agent.

Treatment of iodide melts by metals-getters is considered among the most convenient routines since such a treatment is not accompanied with formations of aggressive volatile substances or appreciably dissolved admixtures in the melts. Ditto, this way of treatment is waste-free since the purification process is not accompanied with emission of pollutants in environment. Zaslavsky [4] used for this purpose spongy titanium. According to the analytical data there was a definite decrease of some admixtures in wastes of Cs| (TI⁺, borates and sulfates) down to mass fraction of $(2\div 4)\cdot 10^{-7}$. Nevertheless, this level of growth melt purity is not enough for manufacturing of the

high-quality single crystals meeting nowadays requirements.

Following development of this approach was initiated in our paper [5] where metallic zirconium was used for removal of oxygen-containing admixtures. The essence of the purification process consists in the running of the following reaction:

$$Zr\downarrow + 2Cs_2O \rightarrow ZrO_2\downarrow + 4Cs.$$
 (2)

The well-known for metallurgy rule says that the equilibrium of reaction of a metal with oxide of other metal (crucible) in condensed phase is shifted to the formation of oxide possessing lower enthalpy of formation per one oxygen atom $(\Delta H^{f}_{MeO_{n}} / n)$ [6].

The application of the said rule for

$$Cs_2O (\Delta H_{Cs_2O}^f = -317 \text{ kJ} \cdot \text{mol}^{-1}),$$

 $TiO_2 (\Delta H_{TiO_2}^f / 2 = -506 \text{ kJ} \cdot \text{mol}^{-1}),$
 $ZrO_2 (\Delta H_{ZrO_2}^f / 2 = -550.2 \text{ kJ} \cdot \text{mol}^{-1})$ and,
e.g. CaO ($\Delta H_{CaO}^f = -635 \text{ kJ} \cdot \text{mol}^{-1}$) predicts
that Zr should be more effective deoxidizing
agent for Csl melt containing oxide ions
than Ti, and this actually takes place [5].
Both metals-getters cannot be used, e.g.,
for purification of CaCl₂ from oxide ion
traces, moreover, ZrO₂ is reduced by Ca in
CaCl₂-containing melts [7], i.e. reaction

$$ZrO_2 \downarrow + 2Ca \rightleftharpoons Zr \downarrow + 2CaO$$
 (3)

runs rightwards but not to the left side.

Returning to $Zr-Csl(O^{2-})$ system it should be noted that the use of pure zirconium gave possibility to decrease of the total concentration of oxide ion in the melt only by a factor of 6 after long-term treatment (ca. 3 h) [5]. Of course, the way of purification should be more attractive after finding ways providing higher efficiency and shortening the time of the melt treatment. One of such ways consists in entering of "metal-getter-noble metal" galvanic couple into the treated melt. As is known, in this case the rate of corrosion (Eq. 1) will increase and the reduction process will run at the surface of nobler metallic component that can compensate the passivation of the getter surface.

However, such a simple approach did not tested yet, although it could be used for other halide melts which preliminary purification from oxides before the main technological process would be rather desirable. The investigation of efficiency of such a galvanic couple formed by zirconium and

platinum is the goal of the present study. Since the rule presented in [6] does not impose constrains on anion composition of purified halide melts that results obtained for Csl melt can be extended to the melts of other alkali metal halides.

2. Experimental

For studying the process of $(Zr + Pt)-Cs|(O^{2-})$ interaction *in situ* we used the potentiometric cell with a membrane oxygen electrode $Pt(O_2)|YSZ$ (where YSZ the $0.9ZrO_2 - 0.1Y_2O_3$ solid electrolyte ceramics):

$$Ag|Ag^{+}(x = 0.03), Cs| \quad \exists \quad Cs|, O^{2-}|YSZ|Pt(O_{2}). \quad (4)$$

This cell was first calibrated with known weights of KOH which served as a donor of oxide ions since its dissociation in molten salts:

$$2\mathsf{O}\mathsf{H}^{-} \to \mathsf{H}_2\mathsf{O}^{\uparrow} + \mathsf{O}^{2-} \tag{5}$$

occurred completely in dry inert atmosphere. This gave us possibility to obtain the dependence of emf(E) of cell (4) on pO $(pO \equiv -\log m_0^{2^-})$, where $m_0^{2^-}$ the equilibrium molality of oxide ions in molten Csl).

Cesium iodide supplied by Aldrich with the mass fraction of the main substance of 0.99999 (kept for a year) was used for the melt preparation. Total concentration of oxygen-containing admixtures in the salt after the melting was ca. $2-5\cdot10^{-4}$ mol·kg⁻¹.

Zr small cylinder with platinum contact was obtained from the Zr rods with the mass fraction of Zr equal to 0.9999 and chemically pure platinum wire. Before the experiment Zr was treated by diluted HCI (mass fraction of HCI is 0.20) to remove the traces of other metals and contaminations. The surface area of Zr cylinders was ca. 0.92 cm^2 .

The calibration of cell (4) was performed by entering of weighted amounts of KOH into Csl melt heated to 973 K. Then equilibrium *emf* value (*E*) was determined by measurement of current emf value (each 5 min, compensational scheme, Poggendorff's bridge) until three sequential measurements gave the same value. According to Eq. (5) two moles of KOH corresponded to one mole of oxide ion. Similarly to data of [5] the calibration plot consisted of two linear sections with slopes, approximately equal to 1.15 RT/F at low oxide ion concentrations: $E(V) = -0.0356 + 0.0976 \cdot pO, E > 0.144 \text{ V}(6)$

and 2.3 RT/F at high oxide ion concentrations:

E(V) = -0.338 + 0.253 pO, E < 0.144 V. (7)

These equations were further used for recalculation of the emf values obtained at the deoxidization process into m_0^{2-}) and pO.

The deoxidization process was studied by placing a Zr cylinder with Pt contact into molten Csl (150 g). After 5 min keeping we measured the dependence of *emf versus* time (each 1-10 min dependently on rate of the *emf* increase) up to the stabilization of *emf*. Then a weight of KOH was added to the melt and the next *emf* dependence was obtained. The procedure was finished when the getter did stop reacting with oxide ions (no directed *emf* changes with the time).

3. Results and discussion

A study of interaction of pure zirconium with oxygen-containing admixtures in molten Csl was described in details in [8]. The surface capacity of the used Zr getter with respect to oxygen is $4.2 \cdot 10^{-5}$ mol·cm⁻². As it has been noted above, the concentration of oxide ion during the purification process is decreased by a factor of 6, i.e., the deoxidizing action of the getter on Csl melt is effective enough and the time of the treatment should be *ca*. 3 h. The deoxidization runs according to kinetics of 2^{nd} order process with respect to O^{2-} , the rate constants is 80 ± 8 kg·mol⁻¹·min⁻¹·cm⁻².

Now let us consider the interaction of "Zr-Pt" galvanic couple with oxygen-containing admixtures in molten cesium iodide. As is known, the action of a galvanic couple consists in the fact that if two contacting metals are placed in aggressive medium, more active metal is subjected to corrosion. Namely, in our case:

$$Zr^0 - 4\overline{e} \rightleftharpoons Zr^{4+} \tag{8}$$

and it can dissolve in aggressive liquids (ionic halide melts). Electrons arising at this process pass into more noble metal (Pt) and take part in reduction processes at its surface. If the reduction process results in formation of insoluble products of the reduction, they are formed near the surface of the more noble metal and do not affect processes running at the surface of more active metal. Nevertheless, in our case sur-

face of zirconium is sequentially passivized be cause of formation of insoluble ZrO_2 :

$$Zr^{4+} + 2O^{2-} \to ZrO_2 \downarrow.$$
(9)

The latter reaction should result in additional contiguous retarding the main process. Let us consider the experimental data. Typical dependences of pO vs. time of the deoxidization process are presented in Fig. 1.

As is seen, addition of the getter to the initial molten Csl leads to relatively fast increase of pO up to a plateau at 8.13 (Fig. 1, curve 1) that corresponds to $7.4 \cdot 10^{-9}$ mol·kg⁻¹ of O²⁻. Comparing this residual concentration with the action of pure zirconium getter was used without the galvanic pair (pO = 4.03, $m_0^{2-} = 9.5 \cdot 10^{-5}$) one can conclude that the addition of platinum contact results in increase of efficiency of the purification process and the residual concentration of oxide ion decreases by a factor of $ca. 10^4$.

After the first addition of KOH (Fig. 1, curve 2) the increase of pO is also observed and its final value is equal to 8.13. This gives the evidence that the surface of ZrO is not passivized completely. Nevertheless, the rate of the deoxidization process becomes slower that takes place due to reduction of the active surface of the getter.

The second addition of potassium hydroxide leads to complete passivation of the getter surface since pO increase stops at value of 4.03 (Fig. 1, curve 3) and the following adding of KOH is not accompanied with interaction, which can be indicated by app reciable pO rise (Fig. 1, curve 4).

To perform quantitative estimations of the deoxidization process in this case it is necessary, in the first turn, to find the surface capacity of zirconium getter with respect to oxide ions. The data presented in Table should be helpful for this purpose, here $w_{\rm KOH}$ is the current mass of added KOH, $\sum w_{\rm KOH}$ the total mass of KOH, $\sum n_{\rm S^{2-}}$



Fig. 1. The dependences of pO versus time (t) for processes of deoxidization of molten Csl by Zr-Pt galvanic pair at 973 K: pure melt (1) and sequential additions of 0.0153 g (2),0.442 g (3) and 0.1250 g (4) of KOH. The mass of the melt is 150 g.

the total quantity of added oxide ions together with the admixtures $(9 \cdot 10^{-5} \text{ mole})$ in 150 g of the melt, pO_{∞} the pO value at the "plateau" section, m_0^{2-} the corresponding molality of O^{2-} , $n_{\infty,O}^{2-}$ the number of moles of O^{2-} after the finishing of the deoxidization process and α is the degree of the surface filling.

Since the second addition of KOH results in complete filling of the getter surface, here α is equal to 1. A number of moles of fixed O²⁻ (n_O^{2-}, fix) is equal to:

$$n_{O^{2^-},fix} = \sum n_{O^{2^-}}^0 - n_{\infty,O^{2^-}} = (10)$$

7.11 \cdot 10^{-4} - 1.4 \cdot 10^{-5} = 6.97 \cdot 10^{-4}.

Knowing the getter surface area ($S_{Zr} = 0.92 \text{ cm}^2$) we can estimate the surface capacity of Zr getter in Zr-Pt galvanic couple (W_{Zr-Pt}):

Initial quantities			Equilibrium quantities			α
w _{кон} , g	$\sum w_{\text{KOH}}$, g	$\sum n_{O^{2-}}^0$, mol	pO_{∞}	m _{O^{2−}} , mol·kg ^{−1}	$n_{\infty,O^{2-}}$, mol	
-	_	_	$9 \cdot 10^{-5}$	8.13	$7.4 \cdot 10^{-9}$	$1.1.10^{-9}$
0.0153	0.0153	$2.27 \cdot 10^{-4}$	8.13	$7.4 \cdot 10^{-9}$	$1.1 \cdot 10^{-9}$	0.325
0.0442	0.0695	$7.11 \cdot 10^{-4}$	4.03	$9.2 \cdot 10^{-5}$	$1.4 \cdot 10^{-5}$	1.0
0.1250	0.1945	$1.83 \cdot 10^{-3}$	1.77	-	_	_

Table. Initial data for estimation of the surface capacity of zirconium getter in galvanic couple "Zr-Pt" with respect to oxide ions in molten Csl at 973 K

$$W_{\text{Zr-Pt}} = n_{\text{O}^{2-}, \text{ fix}} / S_{\text{Zr}} = (6.97 \cdot 10^{-4}) / 0.92 \approx$$

\$\approx 7.6 \cdot 10^{-4} mol \cdot cm^{-2}. (11)\$

This value exceeds similar parameter estimated for Zr getter acting without the galvanic pair by a factor of ca. 18 [8] that underlines the obvious advantage of the use of galvanic couple for the melt deoxidization. Concerning this work this parameter gives us possibility to calculate final value of α after each KOH addition using the following formula:

$$\alpha = \frac{\sum n_{O^{2-}}^{0} - n_{\infty,O^{2-}}}{W_{Zr-Pt}}.$$
 (12)

After calculating α we can proceed to estimation of the kinetic characteristics of the deoxidization. Since at first and second KOH additions there are considerable increase of pO we can consider that the deoxidization process in inclined sections runs irreversibly. Therefore, its running should be subjected to the known kinetic regularities for simple reactions.

Since we can determine current concentration of only oxide ion the running of the process can be described by pseudo-order, i.e., power in which oxide ion concentration enters in the kinetic equation of the following general form:

$$w = k \cdot m_{O^{2-}}^n, \tag{13}$$

where k the rate constants of the purification process.

In the case of n = 1 (the first pseudoorder) the dependence of current (c) concentration from the initial one (c_0) and time (t) is described by the following equations:

$$c = c_0 \cdot \exp(-kt)$$
 or $\ln c = \ln c_0 - kt$. (14)

This means that the dependence of logarithm of concentration from time should be linear. Nevertheless, pO-t dependences $(pO \equiv -\log m_O^{2^-})$ being logarithmic are not linear for the first three additions of KOH that forces to reject the assumption about the 1st pseudo-order. Contrary, dependences $(m_O^{2^-})^{-1} = f(t)$ (which linearity confirms the second kinetic order):

$$c^{-1} = c_0^{-1} + kt \tag{15}$$

presented in Fig. 2 are linear $(r_{xy} \ge 0.99)$. These speculations help us to determine the

These speculations help us to determine the pseudo-order of interaction "Zr-oxygen admixtures" as second one. The obtained result



Fig. 2. The dependences of $(m_0^{2-})^{-1} = f(t)$ for process of deoxidization of molten Csl by Zr-Pt galvanic pair at 973 K: pure melt (1) and sequential additions of 0.0153 g (2), 0.442 g (3) and 0.1250 g (4) of KOH.

completely corresponds to stoichiometry of reaction (2) that leads to formation of ZrO_2 . On the other hand such value of pseudoorder can confirm that reaction (2) is the limiting stage of the process. It should be noted, however, that the deoxidization by getter is complicated by changes of active surface of zirconium which sequentially reduces with the decrease of oxide ion concentration in the melt. The kinetic equation for such a case can be written by such a manner:

$$w = kS_{Zr}(1 - \alpha) \cdot (m_{O^{2-}})^2 =$$
(16)
= $S_{Zr}[k(1 - \alpha)] \cdot (m_{O^{2-}})^2,$

where w the reaction rate, k the rate constant.

To facilitate our calculations of the rate constant we chose for estimation points which pO values exceeded 6, since in this case (initial pO was ca. 4) approximately 99 per cent of the added oxide ions was fixed by zirconium and during further interaction α value was practically constant and equal to final α for each KOH addition. Just owing to this reason plots 1 and 2 depicted in Fig. 2 starts from times 10 and 80 min, respectively. The dependences 1 and 2 in Fig. 2 can be approximated by the following equations:

$$(m_{O^{2-}})^{-1} =$$
 (17)
= -1.7(±5) · 10⁷ + 2.64(±0.1) · 10⁶ · t

and

=

$$(m_{\rm O^{2-}})^{-1} = (18)$$

= -1.26(±0.3) · 10⁸ + 1.76(±0.3) · 10⁶ · t,

respectively. In both cases the reproducibility of the slopes is very good. According Eq. (15) the slopes should be nothing but the rate constants, however, taking into account Eq. (16) they are actually equal to $S_{7r}[k(1-\alpha)]$. The recalculation yields

$$k_1 = \frac{2.64 \cdot 10^6}{(1 - 0.129) \cdot 0.92} =$$
(19)
= 3.29 \cdot 10^6 kg \cdot mol^{-1} \cdot min^{-1} \cdot cm^{-2}

for the initial CsI melt and

$$k_2 = \frac{1.76 \cdot 10^6}{(1 - 0.325) \cdot 0.92} =$$
(20)
= 2.84 \cdot 10^6 kg \cdot mol^{-1} \cdot min^{-1} \cdot cm^{-2}

for the first addition of KOH to the melt. The average rate constant value can be estimated as $3.07 \cdot 10^6$ kg mol⁻¹·min⁻¹·cm⁻² ($S_n = 0.31 \cdot 10^6$) and this value is considerably greater than in the case of using pure zirconium.

The some decrease of the rate constant going from the initial melt to the first KOH addition can be explained in the terms of uniformity of zirconium surface. In the first turn (the initial melt) the most active surface centers are blocked, whereas after the first addition reaction runs on surface centers of the lower activity.

4.Conclusions

So, in the present work we studied the course of the removal of oxide ions from molten CsI by action of galvanic couple "zir-conium-platinum" in potentiometric cell with a membrane oxygen electrode $Pt(O_2)|YSZ$ which was used for the control of oxide ion concentration. According to the obtained results the efficiency of the galvanic couple is considerably higher than that of pure zirconium.

Concerning the physicochemical features of the experiment it should be noted that the running of deoxidization process is subjected to kinetics of 2^{nd} pseudo-order interaction with respect to O^{2-} , rate constant is ca. $3.07 \cdot 10^6$ kg·mol⁻¹·min⁻¹·cm⁻² that is considerably greater than in the case of use of pure zirconium (80 ± 8 kg·mol⁻¹·min⁻¹· cm⁻²). The process stops at pO values near 8 (10^{-8} mol·kg⁻¹ of O^{2-}) and the final concentration of oxide ions is lower than that at the use of Zr by a factor of 10^4 . The effective surface capacity of Zr in the galvanic couple is estimated as $7.4 \cdot 10^{-5}$ mol·cm⁻², i.e. it is higher than that of pure Zr by a factor of 18.

The practical importance of such an approach for purification of halide melts used for different purposes from oxide ion traces seems very promising for other halide melts formed by cesium, rubidium and potassium salts because of essentially higher enthalpies of formation of the corresponding oxides comparing with that of ZrO_2 .

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